

PowerSpeech LOW VOLTAGE ADPCM VOICE SYNTHESIZER

GENERAL DESCRIPTION

The W523X is a programmable speech synthesis IC that utilizes the ADPCM coding method to generate all types of voice effects. The W523X's LOAD and JUMP commands and four programmable registers provide powerful user-programmable functions that make this chip suitable for an extremely wide range of speech IC applications.

The W523X family includes the W5231, W5232, W5233, and W5234. The ROM size of each of these products is shown below:

BODY	W5231	W5232	W5233	W5234
Second	3 Sec	6 Sec	9 Sec	12 Sec

Note: All of the playback lengths are estimated by typical applications.

FEATURES

- Wide operating voltage range: 1.2 to 3.6 volts
- Programmable speech synthesizer
- 4-bit ADPCM synthesis method and 8-bit D/A converter
- RC oscillator with built-in capacitor; voice output frequency typically at 6 KHz
- · Provides 4 trigger inputs
- · Drives 2 flash LEDs for two batteries
- 3 STOP output signals
- Flexible functions programmable through the following:
 - LD (load), JP (jump) commands
 - Four registers: R0, EN, STOP, and MODE
 - Conditional instructions
 - Speech equation
 - Global repeat (GR) setting
- · Programmable power-on initialization (POI), which can be interrupted by trigger inputs
- Interrupt or non-interrupt for rising or falling edge of each trigger pin (this feature determines retriggerable, non-retriggerable, overwrite, and non-overwrite features of each trigger pin)
- LED On/Off control can be set independently in each GO instruction of speech equation
- Independent control of LED1 and LED2
- Total of 256 voice group entries available for programming (including eight hardware and 248 software group entry points)
- 20 to 40 mS debounce time

Publication Release Date: March 1996 Revision A2



• Provides the following mask options:

– LED flash frequency: 3 Hz/6 Hz/Off

- LED flash type: synchronous/alternate

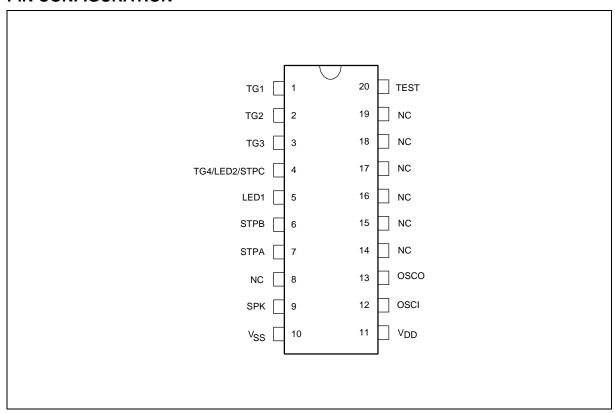
- LED1 section-controlled: Yes/No

- LED2 section-controlled/STPC-controlled

- AUD output current: 1 mA for one battery, 3 mA for two batteries

• Packaged in 20-pin DIP

PIN CONFIGURATION





PIN DESCRIPTION

PIN NO.	PIN NAME	I/O	FUNCTION
1	TG1	_	Trigger Input 1
2	TG2	_	Trigger Input 2
3	TG3	_	Trigger Input 3
4	TG4/LED2/STPC	I/O	Trigger Input 4 or LED 2 or Stop Signal C
5	LED1	0	LED 1
6	STPB	0	Stop Signal B
7	STPA	0	Stop Signal A
8	NC	1	Not Connected
9	SPK	0	Current Output for Speaker
10	Vss	-	Negative Power Supply
11	VDD	-	Positive Power Supply
12	OSCI	I	Oscillator Input Connect Resistor
13	OSCO	0	Oscillator Output Connect Resistor
14	NC	ı	Not Connected
15	NC	1	Not Connected
16	NC	1	Not Connected
17	NC	-	Not Connected
18	NC	-	Not Connected
19	NC	-	Not Connected
20	TEST	I	Test Pin

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	SYMBOL CONDITIONS RATED VALUE		UNIT
Power Supply	VDD-VSS	-0.3 to +5.0		V
Input Voltage	VIN	All Inputs	Vss -0.3 to VDD +0.3	V
Storage Temp.	Tstg		-55 to +150	°C
Operating Temp.	Topr		0 to +70	°C

Note: Exposure to conditions beyond those listed under Absolute Maximum Ratings may adversely affect the life and reliability of the device.



ELECTRICAL CHARACTERISTICS

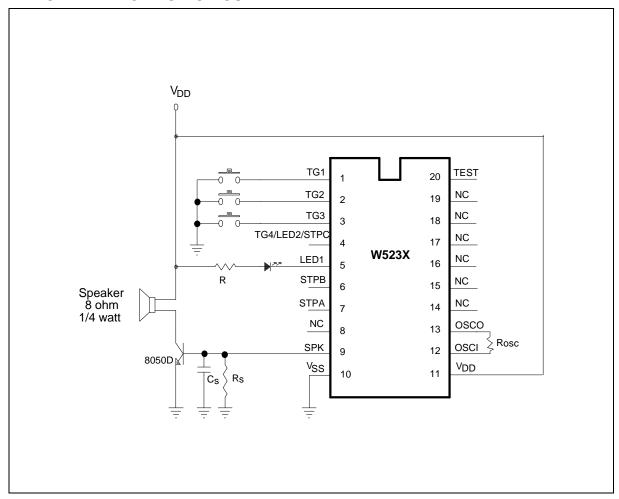
 $(TA = 25^{\circ} C, Vss = 0 V)$

PARAMETER		SYMBOL	CONDITIONS	LIMITS			UNIT
				MIN.	TYP.	MAX.	
Operating Voltage		Vdd	For One or Two Batteries	1.2	2.4	3.6	V
Input Voltage		VIL	All Input Pins	Vss -0.3	-	0.3 VDD	V
		ViH		0.7 Vdd	-	Vdd	
Standby Current		IDD1	VDD = 3 V, No Playing	-	-	0.5	μΑ
		IDD2	VDD = 1.5 V, No Playing	-	-	0.3	
Operating Cu	rrent	IOP1	VDD = 3 V, No Load	-	-	400	μΑ
-		IOP2	VDD = 1.5 V, No Load	-	-	250	
Input Current	For	lin1	VDD = 3 V, VIN = 0 V	-	-	5	μΑ
TG1-TG4		lın2	VDD = 1.5 V, VIN = 0 V	-	-	2.5	
SPK (D/A	Option1	I O1	$V_{DD} = 1.5 \text{ V}, \text{ RL} = 200 \Omega$	-0.8	-1.0	-1.2	mA
Full scale)	Option2	lO2	$VDD = 3 V$, $RL = 200 \Omega$	-2.0	-3.0	-4.0	
		lOL1	VDD = 3V, VOUT = 0.4V	1	-	-	mA
Output Current of SPTC		lOL2	VDD = 1.5V, VOUT = 0.4V	1	-	-	
		Іон1	VDD = 3 V, VOUT = 2.7 V	-0.5	-	-	
		ЮН2	VDD = 1.5 V, VOUT = 1.2 V	-0.3	-	-	
	LED	lo	VDD = 3 V, VOUT = 1 V	6	-	-	mA
Output		lOL1	VDD = 3 V, VOUT = 0.4 V	1	3	-	
Current	STPA	lOL2	VDD = 1.5 V, VOUT = 0.4 V	1	2	-	
	STPB	Іон1	VDD = 3 V, VOUT = 2.7 V	-1	-3	-	
		Іон2	VDD = 1.5 V, VOUT = 1.2 V	-0.3	-	-	
Oscillation Freq.		Fosc ₁	VDD = 3 V, Rosc = Typ.	320	384	460	KHz
		Fosc ₂	VDD = 1.5 V, Rosc = Typ.	320	384	460	
Oscillation Freq. Deviation by Voltage Drop		ΔFosc	F(1.5 V) – F(1.2 V)	0	10	20	%
		Fosc	F(1.5 V)				
Oscillation Freq. Deviation by Voltage Drop		ΔFosc	F(1.8 V) – F(1.5 V)	0	4	7.5	%
		Fosc	F(1.8 V)				
Oscillation Freq. Deviation by Voltage Drop		ΔFosc	F(3.0 V) – F(2.4 V)	0	4	7.5	%
		Fosc	F(3.0 V)				
Input Debounce Time		TDEB	Fosc = 384 KHz	20	30	40	mS

Note: Rosc = Typ.= 100 K Ω for one battery; 110 K Ω for two batteries.



TYPICAL APPLICATION CIRCUIT



Notes:

- 1. In principle, the playing speed determined by ROSC should correspond to the sampling rate during the coding phase. The playing speed may be adjusted by varying ROSC, however.
- 2. Rs is an optional current-dividing resistor. If Rs is added, the resistance should be between 470 and 750 Ω .
- 3. R is used to limit the current on the LED.
- 4. Cs is optional.
- 5. The DC current gain β of transistor 8050 ranges from 120 to 200.
- 6. All unused trigger pins can be left open because of their internal pull-high resistance.
- 7. No warranty for production!





Headquarters

No. 4, Creation Rd. III, Science-Based Industrial Park, Hsinchu, Taiwan TEL: 886-3-5770066 FAX: 886-3-5792697 http://www.winbond.com.tw/ Voice & Fax-on-demand: 886-2-7197006

Taipei Office

11F, No. 115, Sec. 3, Min-Sheng East Rd., Taipei, Taiwan TEL: 886-2-7190505

FAX: 886-2-7197502

Winbond Electronics (H.K.) Ltd.

Rm. 803, World Trade Square, Tower II, 123 Hoi Bun Rd., Kwun Tong, Kowloon, Hong Kong TEL: 852-27516023 FAX: 852-27552064

Winbond Electronics North America Corp. Winbond Memory Lab.

Winbond Microelectronics Corp. Winbond Systems Lab.

2730 Orchard Parkway, San Jose, CA 95134, U.S.A.

TEL: 1-408-9436666 FAX: 1-408-9436668

Note: All data and specifications are subject to change without notice.